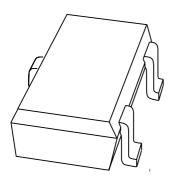
DISCRETE SEMICONDUCTORS

DATA SHEET



BF820WNPN high-voltage transistor

Product data sheet Supersedes data of 1997 Sep 03 2003 Sep 09



NXP Semiconductors Product data sheet

NPN high-voltage transistor

BF820W

FEATURES

- Low current (max. 50 mA)
- High voltage (max. 300 V).

APPLICATIONS

• Telephony and professional communication equipment.

DESCRIPTION

NPN high-voltage transistor in a SOT323 plastic package.

MARKING

TYPE NUMBER	MARKING CODE(1)
BF820W	1V*

Notes

1. * = p: made in Hong Kong. * = t : made in Malaysia.

* = W : made in China.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

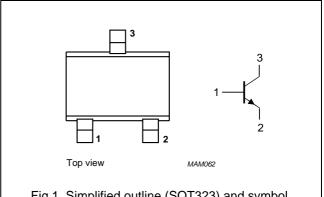


Fig.1 Simplified outline (SOT323) and symbol.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	300	V
V_{CEO}	collector-emitter voltage	open base	_	300	V
I _{CM}	peak collector current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	-	200	mW
h _{FE}	DC current gain	$I_C = 25 \text{ mA}; V_{CE} = 20 \text{ V}$	50	_	
C_{re}	feedback capacitance	$I_C = i_c = 0$; $V_{CB} = 30 \text{ V}$; $f = 1 \text{ MHz}$	_	1.6	pF
f _T	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz}$	60	_	MHz

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	300	V
V_{CEO}	collector-emitter voltage	open base	_	300	V
V _{EBO}	emitter-base voltage	open collector	_	5	V
I _C	collector current (DC)		_	50	mA
I _{CM}	peak collector current		_	100	mA
I _{BM}	peak base current		_	50	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	625	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 200 V	_	10	nA
		I _E = 0; V _{CB} = 200 V; T _j = 150 °C	_	10	μΑ
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	_	50	nA
h _{FE}	DC current gain	I _C = 25 mA; V _{CE} = 20 V	50	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 30 \text{ mA}; I_B = 5 \text{ mA}; \text{ note 1}$	_	600	mV
C _{re}	feedback capacitance	$I_C = i_c = 0$; $V_{CB} = 30 \text{ V}$; $f = 1 \text{ MHz}$	_	1.6	pF
f _T	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 10 \text{ V}; f = 100 \text{ MHz}$	60	_	MHz

Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

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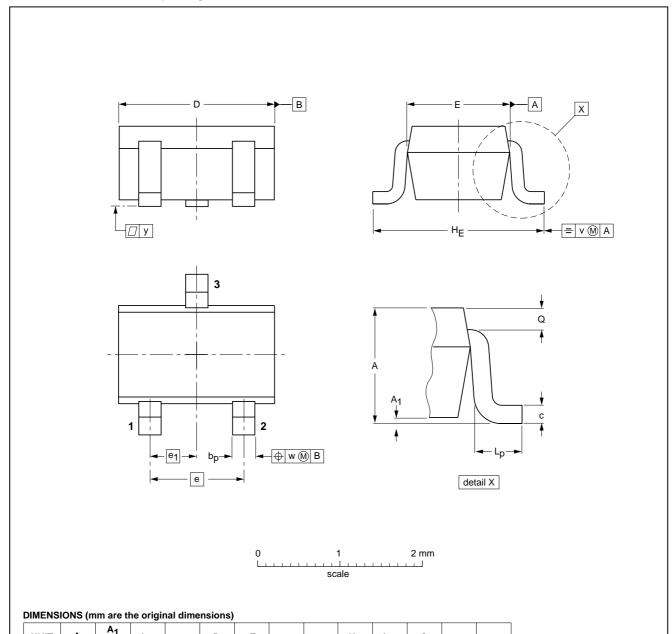
NPN high-voltage transistor

BF820W

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



mm 1.1 0.8 0.1 0.4 0.25 0.10 2.2 1.35 1.15 1.3 0.65 2.2 0.45 0.15 0.45 0.23 0.15 0.23 0.13 0.2	0.2

OUTLINE	REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT323			SC-70			97-02-28

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NPN high-voltage transistor

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DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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2003 Sep 09

NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors. No changes were made to the content, except for the legal definitions and disclaimers.

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